



THE DATASHEET OF 2N6730

2N6728 & 2N6730 Silicon PNP Transistor General Purpose Power Amp, Switch TO-237 Type Package

Description:

The 2N6728 and 2N6730 are silicon NPN power transistors in a TO-237 type package designed for general purpose power amplifier and switching applications.

Absolute Maximum Ratings: ($T_A = +25^\circ\text{C}$ unless otherwise specified)

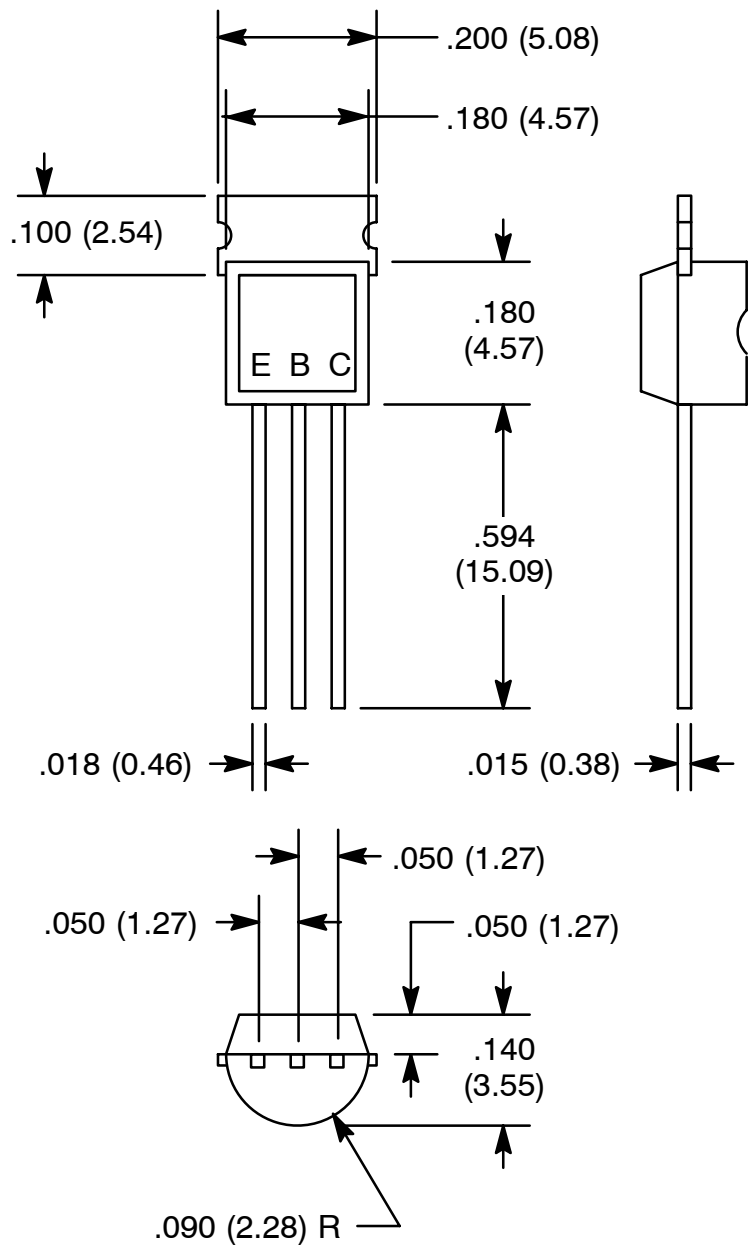
Collector-Base Voltage, V_{CBO}		
2N6728		60V
2N6730		100V
Collector-Emitter Voltage, V_{CEO}		
2N6728		60V
2N6730		100V
Emitter-Base Voltage, V_{EBO}		5V
Continuous Collector Current, I_C		2A
Continuous Base Current, I_B		500mA
Power Dissipation, P_D		
$T_A = +25^\circ\text{C}$		1W
$T_C = +25^\circ\text{C}$		2W
Operating Junction Temperature Range, T_J		-65° to $+150^\circ\text{C}$
Storage Temperature Range, T_{stg}		-65° to $+150^\circ\text{C}$
Thermal Resistance, Junction-to-Ambient, R_{thJA}		125°C/W
Thermal Resistance, Junction-to-Case, R_{thJC}		62.5°C/W

Electrical Characteristics: ($T_A = +25^\circ\text{C}$ unless otherwise specified)

Parameter	Symbol	Condition	Min	Typ	Max	Unit
Collector-Base Breakdown Voltage 2N6728	$V_{(BR)CBO}$	$I_C = 0.1\text{mA}$	60	–	–	V
2N6730			100	–	–	V
Collector-Emitter Breakdown Voltage 2N6728	$V_{(BR)CEO}$	$I_C = 1\text{mA}$	60	–	–	V
2N6730			100	–	–	V
Emitter-Base Breakdown Voltage	$V_{(BR)EBO}$	$I_E = 0.1\text{mA}$	5	–	–	V
Collector Cutoff Current	I_{CBO}	$V_{CB} = \text{Rated } V_{CBO}$	–	–	0.1	μA
Emitter Cutoff Current	I_{EBO}	$V_{EB} = \text{Rated } V_{EBO}$	–	–	10	μA

Electrical Characteristics (Cont'd): ($T_A = +25^{\circ}\text{C}$ unless otherwise specified)

Parameter	Symbol	Condition	Min	Typ	Max	Unit
DC Current Gain	h_{FE}	$V_{CE} = 1\text{V}, I_C = 50\text{mA}$	80	–	–	
		$V_{CE} = 1\text{V}, I_C = 250\text{mA}$	50	–	250	
Collector–Emitter Saturation Voltage	$V_{CE(\text{sat})}$	$I_C = 250\text{mA}, I_B = 10\text{mA}$	–	–	0.5	V
Base–Emitter ON Voltage	$V_{BE(\text{on})}$	$I_C = 250\text{mA}, V_{CE} = 1\text{V}$	–	–	1.2	V
Transition Frequency	f_T	$V_{CE} = 5\text{V}, I_C = 200\text{mA}, f = 20\text{MHz}$	50	–	500	MHz
Output Capacitance	C_{ob}	$V_{CB} = 10\text{V}, I_E = 0, f = 1\text{MHz}$	–	–	30	pF



Looking for pricing, stock, or lifecycle information?

Click below to explore more details on WIN SOURCE:

 View [2N6730](#) on WIN SOURCE

 [NTE](#) Information

Optimize Your Supply Chain with WIN SOURCE Solutions

-  Global Sourcing Solution
-  Obsolete Management
-  Cost Control Management
-  Shortage Management
-  Alternative Solution
-  Excess Inventory Management